

# **Device Modeling Report**

**COMPONENTS:**  
DIODE/ SCHOOTTKY RECTIFIER / STANDARD  
PART NUMBER: M1FS4  
MANUFACTURER: SHINDENGEN

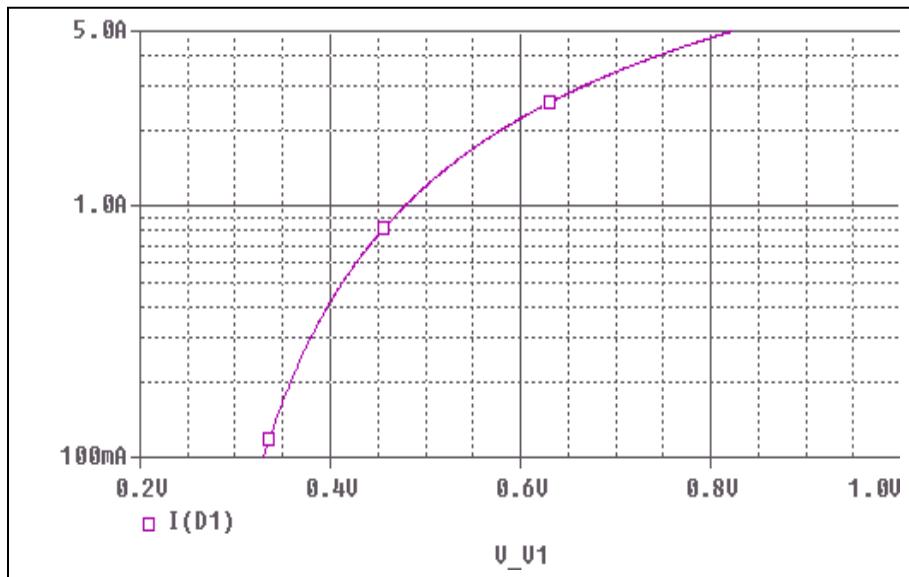


**Bee Technologies Inc.**

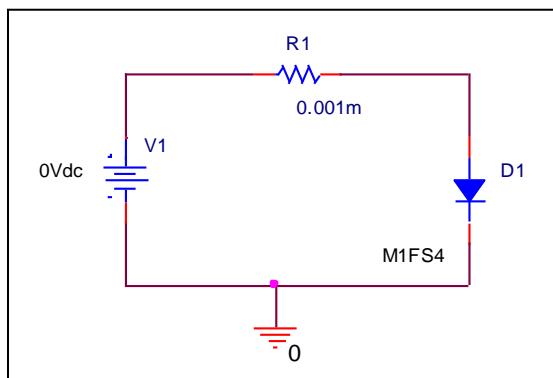
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

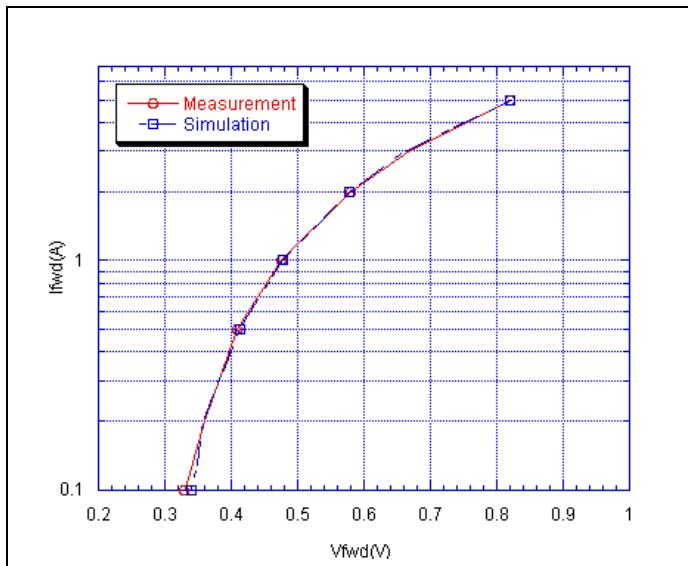


Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result

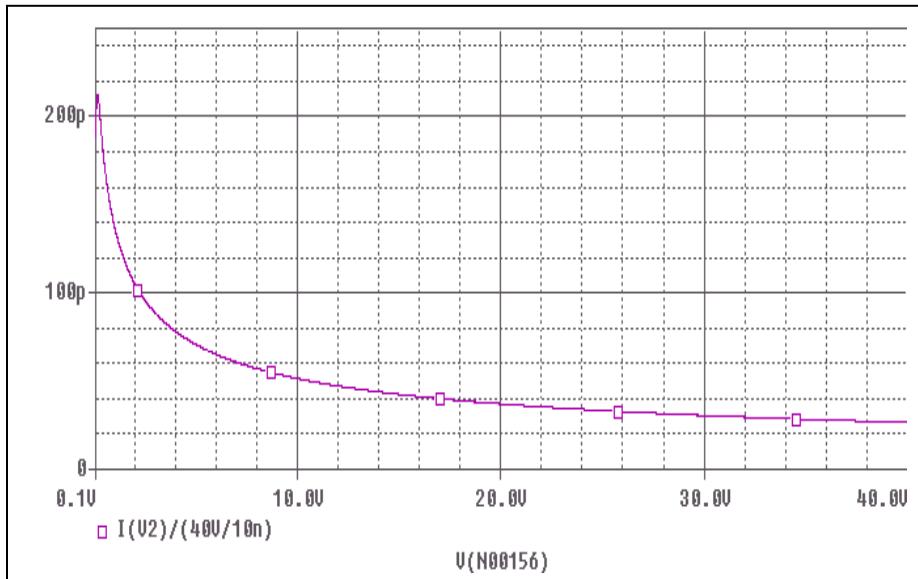


### Simulation Result

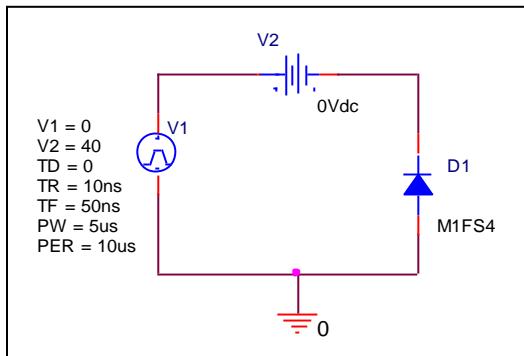
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.1	0.330	0.340	3.03
0.2	0.360	0.358	-0.56
0.5	0.410	0.413	0.73
1	0.475	0.477	0.42
2	0.580	0.577	-0.52
5	0.820	0.821	0.12

## Junction Capacitance Characteristic

### Circuit Simulation Result

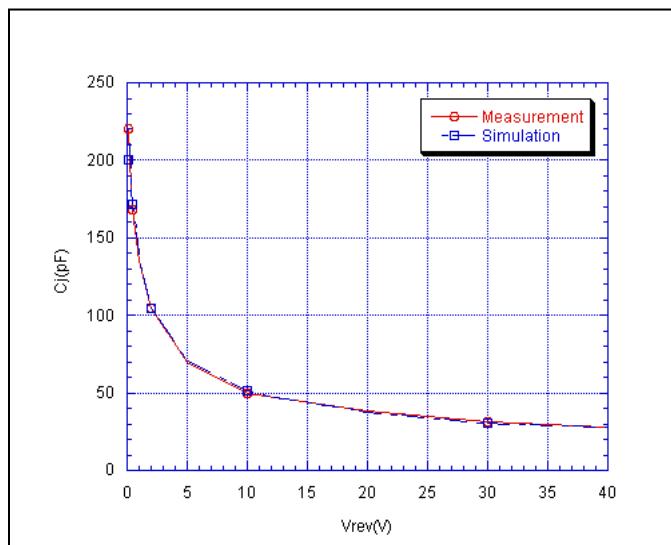


### Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result



### Simulation Result

$V_{rev}(V)$	$C_j(pF)$ Measurement	$C_j(pF)$ Simulation	%Error
0.1	210.00	200.00	-4.76
0.2	205.00	212.00	3.41
0.5	168.00	172.00	2.38
1	135.00	137.00	1.48
2	107.00	105.00	-1.87
5	70.00	70.90	1.29
10	51.00	51.70	1.37
20	38.00	37.30	-1.84
40	27.00	26.70	-1.11